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CONFIRMATION NO. 2816

<b>SERIAL NUMBER</b> 10/667,113	<b>FILING or 371(c) DATE</b> 09/18/2003 <b>RULE</b>	<b>CLASS</b> 257	<b>GROUP ART UNIT</b> 2826	<b>ATTORNEY DOCKET NO.</b> 854063.552D1		
<b>APPLICANTS</b> Gabriele Barlocchi, Cornaredo, ITALY; Flavio Villa, Milano, ITALY; <b>** CONTINUING DATA *****</b> This application is a DIV of 09/545,260 04/07/2000 PAT 6,670,257 <b>** FOREIGN APPLICATIONS *****</b> EUROPEAN PATENT OFFICE (EPO) 99830206.1 04/09/1999 <b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 08/06/2004						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and Acknowledged <u>/FAZLI ERDEM/</u> Examiner's Signature		<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> ITALY	<b>SHEETS DRAWINGS</b> 11	<b>TOTAL CLAIMS</b> 17	<b>INDEPENDENT CLAIMS</b> 4
<b>ADDRESS</b> SEED INTELLECTUAL PROPERTY LAW GROUP PLLC 701 FIFTH AVE SUITE 5400 SEATTLE, WA 98104 UNITED STATES						
<b>TITLE</b> Method for forming horizontal buried channels or cavities in wafers of monocrystalline semiconductor material						
<b>FILING FEE RECEIVED</b> 1936	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit			